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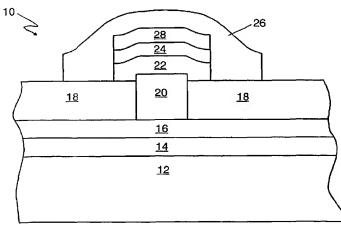
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For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: METAL-TO-METAL ANTIFUSE EMPLOYING CARBON-CONTAINING ANTIFUSE MATERIAL



(57) Abstract: A metal-to-metal antifuse (22) is disposed between two metal interconnect layer in an integrated circuit. An insulating layer (18) is disposed above a lower metal interconnect layer (16). The insulating layer includes a via formed therethrough containing a tungsten plug (20) in electrical contact with the lower metal interconnect layer. The tungsten plug forms a lower electrode of the antifuse. The upper surface of the tungsten plug is planarized with the upper surface of the insulating layer. In a first embodiment, an antifuse material layer (22) comprising amorphous carbon, amorphous carbon doped with hydrogen or fluorine, or amorphous silicon carbide is disposed above the upper surface of the tungsten plug. A layer of a barrier metal (24) disposed over the antifuse material layer forms an upper electrode of the antifuse. An oxide (28) or tungsten hard mask provides high etch selectivity and the possibility to etch barrier metals without affecting the dielectric constant value and mechanical properties of the antifuse material. In a second embodiment, a layer of barrier material is disposed between the top surface of the tungsten plug and the antifuse material layer. An adhesion-promoting layer may be used where amorphous carbon is used as the antifuse material layer.



⁷O 03/030217

INTERNATIONAL SEARCH REPORT

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			PCT/US02/31253			
A. CLASSIFICATION OF SUBJECT MATTER						
IPC(7) : H01L 29/00						
US CL : 257/530						
According to International Patent Classification (IPC) or to both national classification and IPC B. FIELDS SEARCHED						
Minimum documentation searched (classification system followed by classification symbols) U.S.: 257/530, 529, 50, 76						
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched IEEE Transactions						
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used) Please See Continuation Sheet						
C. DOCU	UMENTS CONSIDERED TO BE RELEVANT					
Category *	Citation of document, with indication, where ap	nronriate of the rele	vant nassages	Relevant to claim No.		
Y				1-20, 24-33		
•	LIU et al, A New Metal-to-Metal Antifuse with Amorphous Carbon," IEEE Electr., Device Lett., Vol. 19, No. 9, September 1998, pages 317-319.			1 20, 24 33		
Y,P	US 2002/0100907 A1 (WANG) 01 August 2002 (01.08.2002), pages 1-3.			1-33		
Y	US 5,181,096 A (FOROUHI) 19 January 1993 (19.01.1993), column 7, lines 61-67; column 8, lines 1-6, 56-59.			21, 23, 32		
Y	US 6,114,714 A (GANGOPADHYAY) 05 September 2000 (05.09.2000), column 4, lines 50-67.			2, 3, 14, 30		
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Further	r documents are listed in the continuation of Box C.	See patent	family annex.			
* S	pecial categories of cited documents:			rnational filing date or priority ation but cited to understand the		
"A" document defining the general state of the art which is not considered to be of particular relevance		principle or	theory underlying the inve	ntion		
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"O" document referring to an oral disclosure, use, exhibition or other means			is to a person skilled in the			
"P" document published prior to the international filing date but later than the priority date claimed		"&" document m	ember of the same patent	family		
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	Continuation of B. FIELDS SEARCHED Item 3: USPTO APS EAST search terms: antifuse, insulating layers, tungsten plug, amorphous carbon, silicon carbide, barrier layers					

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